## Today's Outline - October 19, 2016

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- Final presentation


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- Ewald sphere (continued)


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- Modulated Structures


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Homework Assignment \#04:
Chapter 4: 2, 4, 6, 7, 10
due Monday, October 24, 2016

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- Final presentation
- Ewald sphere (continued)
- Modulated Structures
- Crystal Truncation Rods
- Diffuse Scattering
- Debye-Waller factor

Homework Assignment \#04:
Chapter 4: 2, 4, 6, 7, 10
due Monday, October 24, 2016
Homework Assignment \#05:
Chapter 5: 1, 3, 7, 9, 10
due Wednesday, November 2, 2016
No class on Wednesday, November 9, 2016

## Final presentation

(1) Choose paper for presentation

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(2) Clear it with me!

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(3) Do some background research on the technique

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(4) Prepare a 15 minute presentation

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(3) Do some background research on the technique
(4) Prepare a 15 minute presentation
(5) Be ready for questions!

## Ewald sphere \& the reciprocal lattice



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$$
\vec{G}_{h \mid k}=h \vec{a}_{1}^{*}+k \vec{a}_{2}^{*}
$$

## Ewald construction



It is often more convenient to visualize the Ewald sphere by keeping the reciprocal lattice fixed and "rotating" the incident beam to visualize the scattering geometry.

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In directions of $\vec{k}^{\prime}$ (detector position) where there is no reciprocal lattice point, there can be no diffraction peak.

If the crystal is rotated slightly with respect to the incident beam, $\vec{k}$, there may be no Bragg reflections possible at all.

## Polychromatic radiation



## Polychromatic radiation



If $\Delta \vec{k}$ is large enough, there may be more than one reflection lying on the Ewald sphere.

With an area detector, there may then be multiple reflections appearing for a particular orientation (very common with protein crystals where the unit cell is very large).

## Polychromatic radiation



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With an area detector, there may then be multiple reflections appearing for a particular orientation (very common with protein crystals where the unit cell is very large).
In protein crystallography, the area detector is in a fixed location with respect to the incident beam and the crystal is rotated on a spindle so that as Laue conditions are met, spots are produced on the detector at the diffraction angle

## Multiple scattering

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This is the cause of monochromator glitches which sometimes remove intensity but can also add intensity to the reflection the detector is set to measure.

## Laue diffraction



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This technique is useful for taking data on crystals which are changing or may degrade in the beam with a single shot of $x$-rays on a 2 D detector.

$$
\xrightarrow{a}
$$

$$
\begin{aligned}
& 1 x, y, z \\
& 2 x, \bar{y}, \bar{z} \\
& 3 \bar{x}, y, \bar{z} \\
& 4 \bar{x}, \bar{y}, z \\
& 5 z, x, y \\
& 6 \bar{z}, \bar{x}, y \\
& 7 \text { z, } \bar{x}, \bar{y} \\
& 8 \bar{z}, x, \bar{y} \\
& 9 y, z, x \\
& 10 \bar{y}, z, \bar{x} \\
& 11 \bar{y}, \bar{z}, x \\
& 12 y, \bar{z}, \bar{x}
\end{aligned}
$$

$F d \overline{3} m$
F $41 / d 32 / m$
$m \overline{3} m$


## Wyckoff Positions of Group 195 (P23)

| Multiplicity | Wyckoff letter | $\begin{array}{c\|} \hline \text { Site } \\ \text { symmetry } \end{array}$ | Coordinates |
| :---: | :---: | :---: | :---: |
| 12 | j | 1 | $(x, y, z)\left(-x_{1}-y_{1}, z\right)\left(-x_{1} y_{1}-z\right)\left(x_{1}-y_{-}-z\right)$ $\left(z_{1}, x, y\right)\left(z_{1}-x_{1}-y\right)\left(-z_{1}-x_{1}, y\right)\left(-z_{1},-y\right)$ $\left(y_{2}, z_{1}, x\right)\left(-y_{1}, z_{1}-x\right)\left(y_{1}-z_{1}-x\right)\left(-y_{1}-z_{1}, x\right)$ |
| 6 | 1 | 2. | $\begin{aligned} & (x, 1 / 2,1 / 2)(-x, 1 / 2,1 / 2)(1 / 2, x, 1 / 2)(1 / 2,-x, 1 / 2) \\ & (1 / 2,1 / 2, x)(1 / 2,1 / 2,-x) \end{aligned}$ |
| 6 | h | 2. | $\begin{aligned} & \begin{array}{l} (x, 1 / 2,0)(-x, 1 / 2,0)(0, x, 1 / 2)(0,-x, 1 / 2) \\ (1 / 2,0, x)(1 / 2,0,-x) \end{array} \end{aligned}$ |
| 6 | g | $2 .$. | $\begin{aligned} & (x, 0,1 / 2)(-x, 0,1 / 2)(1 / 2, x, 0)(1 / 2,-x, 0) \\ & (0,1 / 2, x)(0,1 / 2,-x) \end{aligned}$ |
| 6 | $f$ | $2 .$. | $\begin{aligned} & (x, 0,0)(-x, 0,0)(0, x, 0)(0,-x, 0) \\ & (0,0, x)(0,0,-x) \end{aligned}$ |
| 4 | e | . 3. | ( $x_{1}, x_{1}$ ) $\left(-x_{1}-x_{1} x\right)\left(-x_{1} x_{1}-x^{\prime}\right)\left(x_{1}-x_{1}-x^{\prime}\right)$ |
| 3 | d | 222. | $(1 / 2,0,0)(0,1 / 2,0)(0,0,1 / 2)$ |
| 3 | c | 222 . | (0,1/2,1/2) (1/2,0,1/2) (1/2,1/2,0) |
| 1 | b | 23. | (1/2,1/2,1/2) |
| 1 | a | 23. | (0,0,0) |

## Wyckoff Positions of Group 227 (Fd-3m) [origin choice 1]



## Diffraction from a Truncated Surface

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With finite sample size, these spots grow in extent and become more diffuse.

If the sample is cleaved and left with flat surface, the diffraction will spread into rods perpendicular to the surface.


## Diffraction from a Truncated Surface



The scattering intensity can be obtained by treating the charge distribution as a convolution of an infinite sample with a step function in the $z$ direction.

## CTR Scattering Factor

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## Dependence on Q

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This removes the infinity and increases the scattering profile of the crystal truncation rod


## Density Effect

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This effect gets larger for larger momentum transfers


